



OMA V:512-1.7

Cryogenic cooling | 512 linear array (InGaAs) | 50 x 500- μ m pixels

The OMA V:512-1.7 from Princeton Instruments is a 512-element, linear photodiode array (PDA) that is excellent for high-performance, near-infrared (NIR) spectroscopy from 0.8 to 1.7 μ m. This InGaAs detector offers outstanding sensitivity with 16-bit digitization and leads the industry with the fastest spectral rate (1800 Hz), lowest system read noise, and software-selectable amplifiers for either high-sensitivity or high-SNR applications. Typical OMA V™ applications include NIR Raman, emission, and absorbance spectroscopy. Cryogenic cooling minimizes dark noise for long exposure times.

Features	Benefits
512 x 1 array	Good spectroscopic format with 25-mm spectral coverage
50 x 500- μ m pixels	Large pixels provide large full well and high signal-to-noise ratio (SNR)
Response from 0.8 to 1.7 μ m with >80% peak quantum efficiency	Excellent NIR sensitivity for demanding spectroscopy applications
Cryogenic cooling	Cools the array from -50 to -100°C to optimize NIR response and minimize dark noise
Software-selectable amplifiers	Exclusive feature provides choice of superior sensitivity or superior SNR
Electronic shutter	Provides integration times from 20 μ sec to many minutes
High spectral data rate	Provides 1800 spectra/second with 1-MHz digitization
Spectrometer compatibility	Easy integration with industry-standard Acton Research SpectraPro® or other leading third-party spectrometers
"USB 2.0 interface" configuration	Seamless, plug-and-play connection to PC notebooks and desktops Easy OEM integration
"PCI interface" configuration	Industry standard for fast data transfer over long distances
WinSpec and PVCAM®	Offers powerful, easy-to-use set of Windows® GUI controls Automates data acquisition, analysis, and display
Linux® drivers and SITK™ plug-in for National Instruments' LabVIEW™	Extends system utility

Specifications

Sensor	Linear InGaAs photodiode array		
Format	512 x 1		
Pixel pitch (µm)	50 wide x 500 tall		
	Minimum	Typical	Maximum
Spectrometric well capacity (Me) low gain high gain	100 4	120 4.5	
System read noise (e-) low gain high gain		5000 520	6000 650
Nominal gain (e-/count) low gain high gain	1525 61	1750 65	2000 76
Dark signal* low gain (ke-/p/s) high gain (ke-/p/s)		15 26	25 30
Response nonlinearity low gain high gain			<1% <2.5%
Response nonuniformity			<10%
Blemish specification	Grade A: <1% defects, minimum of 5 active pixels between any 2 inactive pixels		
Digitization (bits)	16		
Scan rate (MHz)	1		
Spectral rate (Hz)	1800		
Minimum exposure time (µsec)	20		
Thermostating precision	±0.05°C across entire temperature range		
Operating temperature standard range enhanced option	-50 to -100°C -70 to -120°C		

Note: Specifications are preliminary and subject to change.

* includes device's dark current @ -100°C and ambient background signal @ +25°C



Princeton Instruments OMA V:512-1.7

